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Epitaxial Growth of III-Nitride Hetero- and Nanostructures

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Message from the Guest Editors

Research on the epitaxial growth, design and fabrication of III-nitride wide-bandgap semiconductor heteroand nanostructures is driving the development of nextgeneration power/RF electronics and optoelectronic devices. Advances in III-nitride hetero-/nanostructure growth techniques and design protocols promise new devices like photonic crystal nano-/micro-LEDs and lasers, AlGaN/GaN tunneling diodes, high-electron-mobility transistors (HEMTs) with regrown n+-GaN contacts. and multichannel GaN HEMTs. The recent emergence of scandium-doped aluminum nitride (ScxAl1-xN), a relatively new member of the III-nitride family, provides the potential to boost the performance of GaN HEMTs and significantly broadens the application of III-nitrides to ferroelectric devices, RF filters and acoustic sensors.

This Special Issue will address recent progress on the epitaxial growth, material characterization, structural design and engineering, and device applications of III-nitride hetero-/nanostructures, with an emphasis on ScxAl1-xN hetero-/nanostructures.

Specialsue



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Editor-in-Chief

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Message from the Editor-in-Chief

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